

DBL 2036

PAL / SECAM DETECTOR FOR A VTR

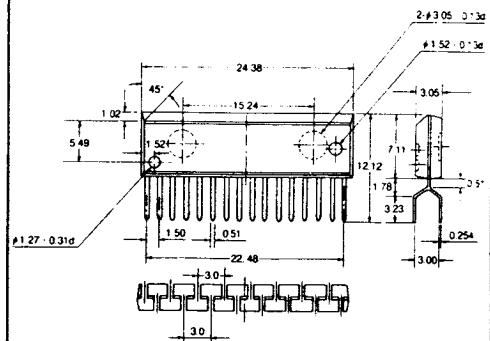
16ZIP

Unit: mm

The DBL 2036 is a monolithic integrated circuit designed for use the PAL / SECAM Signal Detector.

FUNCTION

- Burst Gate and Limit Amp.
- F-V Converter
- Master-Salve F/F
- Level Shifter and Peak detector
- Diff Amp and Comparator



FEATURES

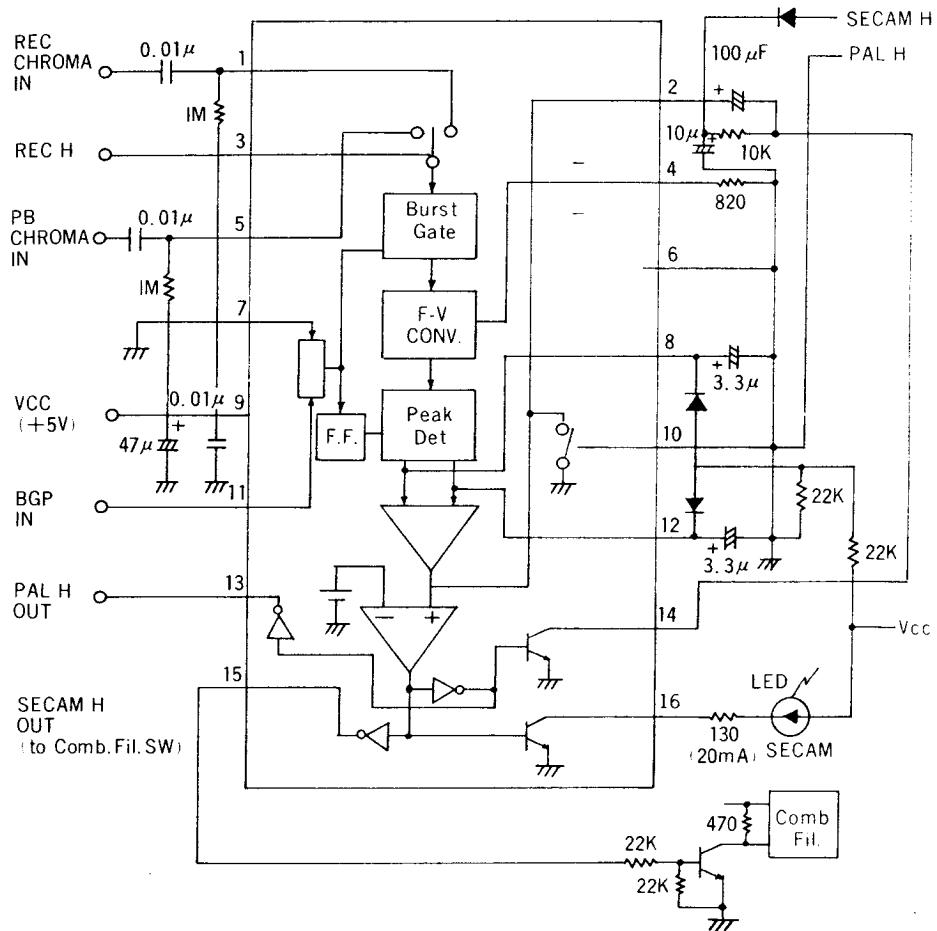
- Possible to detect high sensitivity for variation of noise and burst input level
- Very few external Components
- built-in display LED dirver.
- Possible to use burst Gate Pulse of positive or negative charge
- Operating Supply voltage Range($V_{cc}=4.5V \sim 6.0V$)

MAXIMUM RATINGS($T_a=25^\circ C$)

| Characteristic | Symbol | Rating | Unit |
|-----------------------------|----------------|------------|------|
| Maximum Supply Voltage | $V_{cc}(\max)$ | 7.0 | V |
| Allowable Power Dissipation | $P_d(\max)$ | 130 | mW |
| Operating Temperature | T_{opK} | -10 ~ +70 | °C |
| Storage Temperature | T_{stg} | -55 ~ +150 | °C |

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BLOCK DIAGRAM AND APPLICATION CIRCUIT



note 1 : Pin 7 → input, pin 11 → V_{cc} When BGP is Positive charge.

note 2 : Pin 10 open When pin 10 is not use.

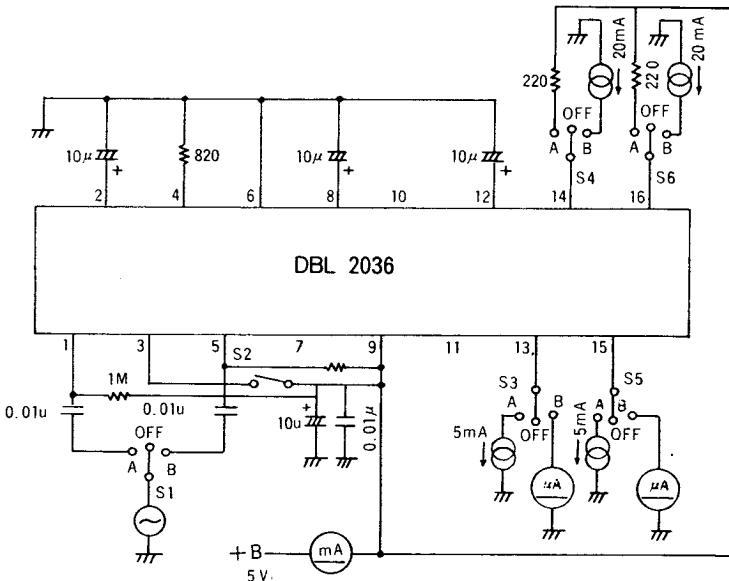
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ELECTRICAL CHARACTERISTICS($T_a=25^\circ\text{C}$, $V_{CC}=5\text{V}$)

| Characteristic | Symbol | Test Condition | Min | Typ | Max | Unit |
|---|-------------------|---------------------------------------|-----|------|------|---------------|
| Dissipation Current | I_{CC} | | 6.7 | 9.6 | 12.4 | mA |
| F-V Variable Gain(PB) | ΔV_P | Difference between 4.4MHZ and 4.25MHz | 75 | 105 | 135 | mV |
| F-V Variable Gain(REC) | ΔV_R | " | 75 | 105 | 135 | mV |
| PAL--SECAM Difference of inverter voltage | $V_{V_{12}}$ | | 35 | 50 | 65 | mV |
| R/P Convert Threshold Voltage | $V_{V_{TH}}$ | | 2.0 | 2.35 | 2.7 | V |
| BG Threshold Voltage I | $V_{V_{TH1}}$ | | 1.5 | 1.7 | 1.9 | V |
| " II | $V_{V_{TH2}}$ | | 3.2 | 3.4 | 3.6 | V |
| Forced PAL Threshold Voltage | $V_{V_{PFTH}}$ | | 1.3 | 1.7 | 2.2 | V |
| Forced SECAM Threshold Voltage | $V_{V_{STH}}$ | | 1.7 | 2.0 | 2.3 | V |
| Detector Output Voltage I | V_{V_D} | ID=5mA | 4.0 | 4.2 | 4.4 | V |
| " II | V_{V_D} | ID=5mA | 4.0 | 4.2 | 4.4 | V |
| Detector output Leak Current I | $I_{D(L)}$ (Leak) | | — | 0 | 5 | μA |
| " II | $I_{D(L)}$ (Leak) | | — | 0 | 5 | μA |
| Pin 12 DC Voltage | $V_{V_{12}}$ | 4.43MHZ 100mV p-p input | 2.1 | 2.6 | 3.1 | V |
| Input Burst Level | $V_{V_{IN}}$ | | 60 | 100 | 200 | mVp-p |
| Drive Saturation Voltage I | $V_{V_{DS1}}$ | ID=20mA | — | 170 | 400 | mV |
| " II | $V_{V_{DS2}}$ | ID=20mA | — | 170 | 400 | mV |

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TEST CIRCUIT



| | S1 | S2 | S3 | S4 | S5 | S6 | Condition |
|-----------------------|-----|-----|-----|-----|-----|-----|---|
| I _{CC} | off | off | off | off | off | off | V ₉ =5V |
| V _P | B | ↓ | ↓ | ↓ | ↓ | ↓ | Input : 100mVp-p, 4.4MHz and 4.25MHz, Measure Voltage Difference of V ₈ (or V ₁₂) |
| V _R | A | on | ↓ | ↓ | ↓ | ↓ | the same as above |
| V ₈₋₁₂ | off | off | ↓ | A | ↓ | ↓ | V ₇ =0V, V ₁₁ =5V, V ₈ =1.9V, V ₁₂ =1.9V+α, V ₁₄ >4V, α(0V↑) |
| V _{3TH} | ↓ | ↓ | ↓ | off | ↓ | ↓ | V ₁ =V ₇ =V ₁₁ =0V, V ₈ <0.1V, Measure V ₃ (0V↑) |
| V _{7TH} | ↓ | ↓ | ↓ | ↓ | ↓ | ↓ | V ₁₁ =5V, V ₈ >1.0V, Measure V ₇ (0V↑) |
| V _{11TH} | ↓ | ↓ | ↓ | ↓ | ↓ | ↓ | V ₇ =0V, V ₈ >1.0V, Measure V ₁₁ (5V↓) |
| V _{10TH} | ↓ | ↓ | ↓ | ↓ | ↓ | A | V ₇ =V ₁₁ =0V, V ₁₆ >4V, Measure V ₁₀ (0V↑) |
| V _{2TH} | ↓ | ↓ | ↓ | A | ↓ | off | V ₈ =V ₁₂ =3V, V ₁₄ >4V, Measure V ₂ (0V↑) |
| V ₁₃ | ↓ | ↓ | A | off | ↓ | ↓ | Pin13 Voltage of V ₂ =0V, Drive Current 5mA |
| V ₁₅ | ↓ | ↓ | off | ↓ | A | ↓ | Pin15 Voltage of V ₂ =3V, Drive Current 5mA |
| I _B (leak) | ↓ | ↓ | B | ↓ | off | ↓ | Drive Current when V ₂ =3V, Pin 13=GND |
| I _B (leak) | ↓ | ↓ | off | ↓ | B | ↓ | Drive Current when V ₂ =0V, Pin 15=GND |
| V ₁₄ (sat) | ↓ | ↓ | ↓ | B | off | ↓ | V ₂ =0V, Measure Pin14 Voltage, Drive Current 20mA |
| V ₁₆ (sat) | ↓ | ↓ | ↓ | off | ↓ | B | V ₂ =3V, Measure Pin16 Voltage, Drive Current 20mA |

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I/O FUNCTION

| Pin | Function | I/O Impedance | DC voltage | Comment |
|-----|-----------------|--------------------|-----------------|-----------------|
| 1 | REC Chroma in | 10Kohm | 4.1V | |
| 2 | SECAM Holder | | | SECAM>2.0V |
| 3 | R/P Control | | 0V (PB) | REC>2.4V |
| 4 | Current Source | Open Emitter | 410mV | |
| 5 | PB Chroma In | 10Kohm | 4.1V | |
| 6 | GND | | 0V | |
| 7 | BGP In | Pulse | | Burst Gate>1.7V |
| 8 | Peak Filter 1 | Emitter follower | | |
| 9 | V _{cc} | | 5V | |
| 10 | PAL high In | | 0V | Forced PAL>1.7V |
| 11 | BGP In | Pulse | | Burst Gate>3.4V |
| 12 | Peak Filter 2 | Emitter follower | | |
| 13 | PAL high out | | 4.1V (PAL) | Until 5mA |
| 14 | PAL Drive | NPN Open Collector | | Until 25mA |
| 15 | SECAM high out | | 4.1V (SECAM) | Until 5mA |
| 16 | SECAM Drive | NPN Open Collector | | Until 25mA |